

8-Channel DAS with 18-Bit, Bipolar, Simultaneous Sampling ADC

Data Sheet AD7608

FEATURES

8 simultaneously sampled inputs
True bipolar analog input ranges: ±10 V, ±5 V

Single 5 V analog supply and 2.3 V to 5.25 V $\ensuremath{\text{V}}_{\text{DRIVE}}$

Fully integrated data acquisition solution

Analog input clamp protection

Input buffer with 1 $M\Omega$ analog input impedance

Second-order antialiasing analog filter

On-chip accurate reference and reference buffer

18-bit ADC with 200 kSPS on all channels

Oversampling capability with digital filter

Flexible parallel/serial interface

SPI/QSPI™/MICROWIRE™/DSP compatible

Pin compatible solutions from 14-bits to 18-bits

Performance

7 kV ESD rating on analog input channels

98 dB SNR, -107 dB THD Low power: 100 mW Standby mode: 25 mW

64-lead LQFP package

APPLICATIONS

Power line monitoring and protection systems

Multiphase motor controls

Instrumentation and control systems

Multiaxis positioning systems

Data acquisition systems (DAS)

COMPANION PRODUCTS

External References: ADR421, ADR431

Digital Isolators: ADuM1402, ADuM5000, ADuM5402
Voltage Regulator Design Tool: ADIsimPower, Supervisor

Parametric Search

Complete list of complements on AD7608 product page

Table 1. High Resolution, Bipolar Input, Simultaneous

Sampling DAS Solutions

Resolution	Single- Ended Inputs	True Differential Inputs	Number of Simultaneous Sampling Channels
18 Bits	AD7608 ¹	AD7609	8
16 Bits	AD7606B		8
	AD7606		8
	AD7606-6		6
	AD7606-4		4
14 Bits	AD7607		8

¹ Protected by U.S. Patent Number 8,072,360.

FUNCTIONAL BLOCK DIAGRAM

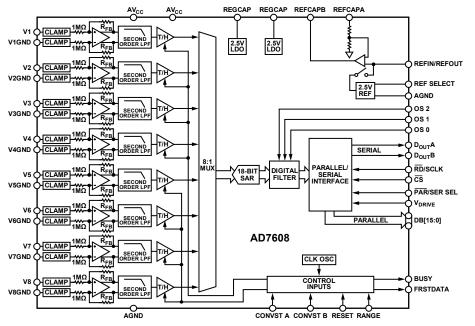


Figure 1.

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4/2011—Revision 0: Initial Version

GENERAL DESCRIPTION

The AD7608 is an 18-bit, 8-channel simultaneous sampling, analog-to-digital data acquisition system (DAS). The part contains analog input clamp protection, a second-order antialiasing filter, a track-and-hold amplifier, an 18-bit charge redistribution successive approximation analog-to-digital converter (ADC), a flexible digital filter, a 2.5 V reference and reference buffer, and high speed serial and parallel interfaces.

The AD7608 operates from a single 5 V supply and can accommodate ± 10 V and ± 5 V true bipolar input signals while sampling at throughput rates up to 200 kSPS for all channels.

The input clamp protection circuitry can tolerate voltages up to ± 16.5 V. The AD7608 has 1 $M\Omega$ analog input impedance regardless of sampling frequency. The single supply operation, on-chip filtering, and high input impedance eliminate the need for driver op amps and external bipolar supplies. The AD7608 antialiasing filter has a 3 dB cutoff frequency of 22 kHz and provides 40 dB antialias rejection when sampling at 200 kSPS. The flexible digital filter is pin driven, yields improvements in SNR, and reduces the 3 dB bandwidth.

SPECIFICATIONS

 $V_{\text{REF}} = 2.5 \text{ V external/internal, AV}_{\text{CC}} = 4.75 \text{ V to } 5.25 \text{ V}, V_{\text{DRIVE}} = 2.3 \text{ V to } 5.25 \text{ V}; f_{\text{SAMPLE}} = 200 \text{ kSPS, } T_{\text{A}} = T_{\text{MIN}} \text{ to } T_{\text{MAX}}, \text{ unless otherwise noted.} \\ ^{1} \text{ AV}_{\text{CC}} = 4.75 \text{ V to } 5.25 \text{ V}; V_{\text{DRIVE}} = 2.3 \text{ V to } 5.25 \text{ V}; f_{\text{SAMPLE}} = 200 \text{ kSPS, } T_{\text{A}} = T_{\text{MIN}} \text{ to } T_{\text{MAX}}, \text{ unless otherwise noted.} \\ ^{1} \text{ AV}_{\text{CC}} = 4.75 \text{ V to } 5.25 \text{ V}; V_{\text{DRIVE}} = 2.3 \text{ V to } 5.25 \text{ V}; f_{\text{SAMPLE}} = 200 \text{ kSPS, } T_{\text{A}} = T_{\text{MIN}} \text{ to } T_{\text{MAX}}, \text{ unless otherwise noted.} \\ ^{1} \text{ AV}_{\text{CC}} = 4.75 \text{ V to } 5.25 \text{ V}; f_{\text{SAMPLE}} = 2.00 \text{ kSPS, } T_{\text{A}} = T_{\text{MIN}} \text{ to } T_{\text{MAX}}, \text{ unless otherwise noted.} \\ ^{1} \text{ AV}_{\text{CC}} = 4.75 \text{ V to } 5.25 \text{ V}; f_{\text{SAMPLE}} = 2.00 \text{ kSPS, } T_{\text{A}} = T_{\text{MIN}} \text{ to } T_{\text{MAX}}, \text{ unless otherwise noted.} \\ ^{1} \text{ AV}_{\text{CC}} = 4.75 \text{ V to } 5.25 \text{ V}; f_{\text{SAMPLE}} = 2.00 \text{ kSPS, } T_{\text{A}} = T_{\text{MIN}} \text{ to } T_{\text{MAX}}, \text{ unless otherwise noted.} \\ ^{1} \text{ AV}_{\text{CC}} = 4.75 \text{ V to } 5.25 \text{ V}; f_{\text{A}} = T_{\text{MIN}} \text{ to } T_{\text{MAX}}, \text{ unless otherwise noted.} \\ ^{1} \text{ AV}_{\text{CC}} = 4.75 \text{ V to } 5.25 \text{ V}; f_{\text{A}} = T_{\text{MAX}}, \text{ to } T_{\text{A}} = T_{\text{A}} = T_{\text{MAX}}, \text{ to } T_{\text{A}} = T_{\text{A}}$

Table 2.

Parameter	Test Conditions/Comments	Min	Тур	Max	Unit
DYNAMIC PERFORMANCE	f _{IN} = 1 kHz sine wave unless otherwise noted				
Signal-to-Noise Ratio (SNR) ^{2, 3}	Oversampling by 16; \pm 10 V range; $f_{IN} = 130$ Hz	98	99.5		dB
	Oversampling by 16; \pm 5 V range; $f_{IN} = 130 \text{ Hz}$	95.5	97.5		dB
	No oversampling; ±10 V range	89.5	90.9		dB
	No oversampling; ±5 V range	88.5	90		dB
Signal-to-(Noise + Distortion) (SINAD) ²	No oversampling; ±10 V range	88.5	90.5		dB
signal to (Holse Distortion) (Silvito)	No oversampling; ±5 V range	88	89.5		dB
Dynamic Range	No oversampling; ±10 V range		91.5		dB
Dynamic hange	No oversampling; ±10 V range		90.5		dB
Total Harmonic Distortion (TUD)?	No oversampling, ±3 v range		90.3 –107	-95	dВ
Total Harmonic Distortion (THD) ²				-95	
Peak Harmonic or Spurious Noise (SFDR) ²	6 4111 (1 44111		-108		dB
Intermodulation Distortion (IMD) ²	fa = 1 kHz, fb = 1.1 kHz				
Second-Order Terms			-110		dB
Third-Order Terms			-106		dB
Channel-to-Channel Isolation ²	f _{IN} on unselected channels up to 160 kHz		-95		dB
ANALOG INPUT FILTER					
Full Power Bandwidth	−3 dB, ±10 V range		23		kHz
	−3 dB, ±5 V range		15		kHz
	−0.1 dB, ±10 V range		10		kHz
	−0.1 dB, ±5 V range		5		kHz
t _{GROUP DELAY}	±10 V range		11		μs
CONSTRUCTION OF THE CONSTR	±5 V range		15		μs
DC ACCURACY					F
Resolution	No missing codes	18			Bits
Differential Nonlinearity ²	The missing codes	.0	±0.75	-0.99/+2.6	LSB ⁴
Integral Nonlinearity ²			±2.5	±7.5	LSB
Total Unadjusted Error (TUE)	±10 V range		±15	±1.5	LSB
Total offacjusted Effor (TOE)	±5 V range		±40		LSB
Desitive Full Carlo Funa v ² 5	External reference			.120	
Positive Full-Scale Error ^{2, 5}			±15	±128	LSB
	Internal reference		±40		LSB
Positive Full-Scale Error Drift	External reference		±2		ppm/°0
_	Internal reference		±7		ppm/°0
Positive Full-Scale Error Matching ²	±10 V range		12	95	LSB
	±5 V range		30	128	LSB
Bipolar Zero Code Error ^{2, 6}	±10 V range		±3.5	±24	LSB
	± 5 V range		±3.5	±48	LSB
Bipolar Zero Code Error Drift	±10 V range		10		μV/°C
	±5V range		5		μV/°C
Bipolar Zero Code Error Matching ²	±10 V range		3	30	LSB
	±5 V range		21	65	LSB
Negative Full-Scale Error ^{2,5}	External reference		±15	±128	LSB
regulive Fall Scale LITO	Internal reference		±40	±120	LSB
Negative Full-Scale Error Drift	External reference				ppm/°
rvegative ruii-scale EITOI DIIIL			±4		
Negative Full Code Form Addatable of	Internal reference		±8	05	ppm/°(
Negative Full-Scale Error Matching ²	±10 V range		12	95	LSB
	±5 V range	1	30	128	LSB

Parameter	Test Conditions/Comments	Min	Тур	Max	Unit
ANALOG INPUT					
Input Voltage Ranges	RANGE = 1			±10	V
, , ,	RANGE = 0			±5	V
Analog Input Current	10 V; see Figure 28		5.4		μΑ
	5 V; see Figure 28		2.5		μA
Input Capacitance ⁷			5		pF
Input Impedance			1		MΩ
REFERENCE INPUT/OUTPUT					
Reference Input Voltage Range		2.475	2.5	2.525	V
DC Leakage Current				±1	μΑ
Input Capacitance ⁷	REF SELECT = 1		7.5		pF
Reference Output Voltage	REFIN/REFOUT		2.49/		v
, -			2.505		
Reference Temperature Coefficient			±10		ppm/°0
LOGIC INPUTS					
Input High Voltage (V _{INH})		$0.9 \times V_{DRIVE}$			V
Input Low Voltage (V _{INL})				$0.1 \times V_{DRIVE}$	V
Input Current (I _{IN})				±2	μΑ
Input Capacitance (C _{IN}) ⁷			5		pF
LOGIC OUTPUTS					
Output High Voltage (Voн)	$I_{SOURCE} = 100 \mu A$	V _{DRIVE} − 0.2			V
Output Low Voltage (Vol)	$I_{SINK} = 100 \mu A$			0.2	V
Floating-State Leakage Current			±1	±20	μΑ
Floating-State Output Capacitance ⁷			5		pF
Output Coding	Twos complement				
CONVERSION RATE					
Conversion Time	All eight channels included; see Table 3		4		μs
Track-and-Hold Acquisition Time			1		μs
Throughput Rate	Per channel, all eight channels included			200	kSPS
POWER REQUIREMENTS					
AV_CC		4.75		5.25	V
V _{DRIVE}		2.3		5.25	V
I _{TOTAL}	Digital inputs = 0 V or V _{DRIVE}				
Normal Mode (Static)			16	22	mA
Normal Mode (Operational)8	$f_{SAMPLE} = 200 \text{ kSPS}$		20	27	mA
Standby Mode			5	8	mA
Shutdown Mode			2	11	μΑ
Power Dissipation					
Normal Mode (Static)			80	115.5	mW
Normal Mode (Operational) ⁸	f _{SAMPLE} = 200 kSPS		100	142	mW
Standby Mode			25	42	mW
Shutdown Mode			10	58	μW

¹ Temperature range for B version is -40°C to +85°C.

 ² See the Terminology section.
 3 This specification applies when reading during a conversion or after a conversion. If reading during a conversion in parallel mode with V_{DRNE} = 5 V, SNR typically reduces by 1.5 dB and THD by 3 dB.
 4 LSB means least significant bit. With ±5 V input range, 1 LSB = 38.14 μV. With ±10 V input range, 1 LSB = 76.29 μV.
 5 The consense of the facility of the full temporature range variation and contribution from the internal reference buffer but do not include the error contribution from

⁵ These specifications include the full temperature range variation and contribution from the internal reference buffer but do not include the error contribution from the external reference.

 ⁶ Bipolar zero code error is calculated with respect to the analog input voltage.
 ⁷ Sample tested during initial release to ensure compliance.
 ⁸ Operational power/current figure includes contribution when running in oversampling mode.

TIMING SPECIFICATIONS

 $AV_{CC} = 4.75 \text{ V}$ to 5.25 V, $V_{DRIVE} = 2.3 \text{ V}$ to 5.25 V, $V_{REF} = 2.5 \text{ V}$ external reference/internal reference, $T_A = T_{MIN}$ to T_{MAX} , unless otherwise noted. ¹

Table 3.

	Limit	at T _{MIN} , 7	T _{MAX}			
Parameter	Min	Тур	Max	Unit	Description	
PARALLEL/SERIAL MODE						
tcycle					1/throughput rate	
			5	μs	Parallel mode, reading during or after conversion; or serial mode: V _{DRIVE} = 3.3 V to 5.25 V, reading during a conversion using D _{OUT} A and D _{OUT} B lines	
		5		μs	Serial mode reading during conversion; VDRIVE = 2.7 V	
			10.5	μs	Serial mode reading after a conversion; $V_{DRIVE} = 2.3 \text{ V}$, $D_{OUT}A$ and $D_{OUT}B$ lines	
tconv					Conversion time	
	3.45	4	4.2	μs	Oversampling off	
	7.87		9.1	μs	Oversampling by 2	
	16.05		18.8	μs	Oversampling by 4	
	33		39	μs	Oversampling by 8	
	66		78	μs	Oversampling by 16	
	133		158	μs	Oversampling by 32	
	257		315	μs	Oversampling by 64	
t wake-up standby			100	μs	STBY rising edge to CONVST x rising edge; power-up time from standby mode	
t wake-up shutdown						
Internal Reference			30	ms	STBY rising edge to CONVST x rising edge; power-up time from shutdown mode	
External Reference			13	ms	STBY rising edge to CONVST x rising edge; power-up time from shutdown mode	
treset	50			ns	RESET high pulse width	
t _{OS_SETUP}	20			ns	BUSY to OS x pin setup time	
tos_HOLD	20			ns	BUSY to OS x pin hold time	
t ₁			40	ns	CONVST x high to BUSY high	
t_2	25			ns	Minimum CONVST x low pulse	
t ₃	25			ns	Minimum CONVST x high pulse	
t ₄	0			ns	BUSY falling edge to CS falling edge setup time	
t_5^2			0.5	ms	Maximum delay allowed between CONVST A, CONVST B rising edges	
t ₆			25	ns	Maximum time between last $\overline{\text{CS}}$ rising edge and BUSY falling edge	
t ₇	25			ns	Minimum delay between RESET low to CONVST x high	
PARALLEL/READ OPERATION					,	
t ₈	0			ns	CS to RD setup time	
t ₉	0			ns	CS to RD hold time	
t ₁₀					RD low pulse width	
	16			ns	V _{DRIVE} above 4.75 V	
	21			ns	V _{DRIVE} above 3.3 V	
	25			ns	V _{DRIVE} above 2.7 V	
	32			ns	V _{DRIVE} above 2.3 V	
t ₁₁	15			ns	RD high pulse width	
t ₁₂	22			ns	CS high pulse width (see Figure 5); CS and RD linked	

	Limit	at T _{MIN} , 1	Гмах		
Parameter	Min	Тур	Max	Unit	Description
t ₁₃					Delay from CS until DB[15:0] three-state disabled
			16	ns	V _{DRIVE} above 4.75 V
			20	ns	V _{DRIVE} above 3.3 V
			25	ns	V _{DRIVE} above 2.7 V
			30	ns	V _{DRIVE} above 2.3 V
t ₁₄ ³					Data access time after RD falling edge
			16	ns	V _{DRIVE} above 4.75 V
			21	ns	V _{DRIVE} above 3.3 V
			25	ns	V _{DRIVE} above 2.7 V
			32	ns	V _{DRIVE} above 2.3 V
t ₁₅	6			ns	Data hold time after RD falling edge
t ₁₆	6			ns	CS to DB[15:0] hold time
t ₁₇			22	ns	Delay from CS rising edge to DB[15:0] three-state enabled
SERIAL READ OPERATION				113	being from estising eage to bb[15.0] times state chables
f _{SCLK}					Frequency of serial read clock
ISCLK			23.5	MHz	V _{DRIVE} above 4.75 V
			23.5 17	MHz	V _{DRIVE} above 4.73 V
			14.5	MHz	V _{DRIVE} above 3.3 V
			11.5	MHz	V _{DRIVE} above 2.3 V
t ₁₈			11.5	101112	Delay from CS until DoutA/DoutB three-state disabled/delay from CS until
118					MSB valid
			15	ns	V _{DRIVE} above 4.75 V
			20	ns	V _{DRIVE} above 3.3 V
			30	ns	V _{DRIVE} = 2.3 V to 2.7 V
t ₁₉ ³			30	113	Data access time after SCLK rising edge
Cla			17	ns	V _{DRIVE} above 4.75 V
			23	ns	V _{DRIVE} above 3.3 V
			27	ns	V _{DRIVE} above 2.7 V
			34	ns	V _{DRIVE} above 2.3 V
t ₂₀	0.4 t _{SCLK}		34	ns	SCLK low pulse width
t ₂₁	0.4 tSCLK	•		ns	SCLK high pulse width
t ₂₂	7	•		113	SCLK rising edge to DoutA/DoutB valid hold time
t ₂₃	,		22	ns	CS rising edge to DoutA/DoutB three-state enabled
				113	CS fishing edge to boothy booth timee-state enabled
FRSTDATA OPERATION					Delay from CS falling edge until FRSTDATA three-state disabled
t ₂₄			1.5		V _{DRIVE} above 4.75 V
			15	ns	
			20	ns	V _{DRIVE} above 3.3 V V _{DRIVE} above 2.7 V
			25	ns	
			30	ns	V _{DRIVE} above 2.3 V
t ₂₅			4.5	ns	Delay from CS falling edge until FRSTDATA high, serial mode
			15	ns	V _{DRIVE} above 4.75 V
			20	ns	V _{DRIVE} above 3.3 V
			25	ns	V _{DRIVE} above 2.7 V
			30	ns	V _{DRIVE} above 2.3 V
t_{26}			4 -		Delay from RD falling edge to FRSTDATA high
			16	ns	V _{DRIVE} above 4.75 V
			20	ns	V _{DRIVE} above 3.3 V
			25	ns	V _{DRIVE} above 2.7 V
			30	ns	V _{DRIVE} above 2.3 V

	Limit at T _{MIN} , T _{MAX}				
Parameter	Min	Тур	Max	Unit	Description
t ₂₇					Delay from RD falling edge to FRSTDATA low
			19	ns	V _{DRIVE} = 3.3 V to 5.25 V
			24	ns	$V_{DRIVE} = 2.3 \text{ V to } 2.7 \text{ V}$
t ₂₈					Delay from 16 th SCLK falling edge to FRSTDATA low
			17	ns	$V_{DRIVE} = 3.3 \text{ V to } 5.25 \text{ V}$
			22	ns	$V_{DRIVE} = 2.3 \text{ V to } 2.7 \text{ V}$
t ₂₉			24	ns	Delay from CS rising edge until FRSTDATA three-state enabled

¹ Sample tested during initial release to ensure compliance. All input signals are specified with t_R = t_F = 5 ns (10% to 90% of V_{DD}) and timed from a voltage level of 1.6 V.

Timing Diagrams

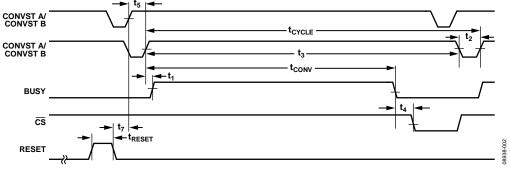


Figure 2.CONVST x Timing—Reading After a Conversion

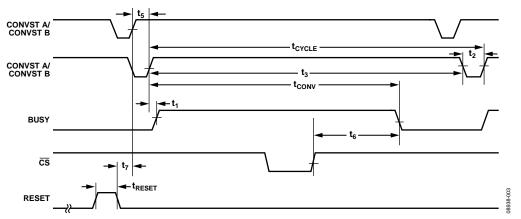


Figure 3. CONVST x Timing—Reading During a Conversion

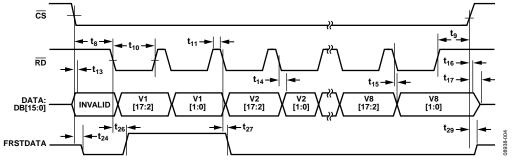


Figure 4. Parallel Mode Separate \overline{CS} and \overline{RD} Pulses

² The delay between the CONVST x signals was measured as the maximum time allowed while ensuring a <40 LSB performance matching between channel sets.

³ A buffer is used on the data output pins for these measurements, which is equivalent to a load of 20 pF on the output pins.

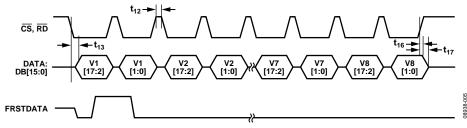


Figure 5. CS and RD Linked Parallel Mode

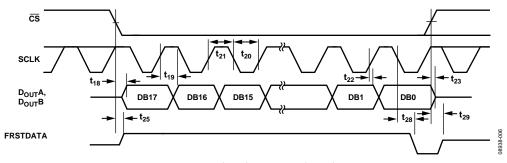


Figure 6. Serial Read Operation (Channel 1)

ABSOLUTE MAXIMUM RATINGS

 $T_A = 25$ °C, unless otherwise noted.

Table 4.

Parameter	Rating
AV _{CC} to AGND	-0.3 V to +7 V
V _{DRIVE} to AGND	$-0.3 \text{ V to AV}_{CC} + 0.3 \text{ V}$
Analog Input Voltage to AGND ¹	±16.5 V
Digital Input Voltage to AGND	$-0.3 \text{ V to V}_{DRIVE} + 0.3 \text{ V}$
Digital Output Voltage to AGND	$-0.3 \text{ V to V}_{DRIVE} + 0.3 \text{ V}$
REFIN to AGND	-0.3 V to AV _{CC} + 0.3 V
Input Current to Any Pin Except Supplies ¹	±10 mA
Operating Temperature Range	
B Version	−40°C to +85°C
Storage Temperature Range	−65°C to +150°C
Junction Temperature	150°C
Pb/SN Temperature, Soldering	
Reflow (10 sec to 30 sec)	240 (+0)°C
Pb-Free Temperature, Soldering Reflow	260 (+0)°C
ESD (All Pins Except Analog Inputs)	2 kV
ESD (Analog Input Pins Only)	7 kV

¹ Transient currents of up to 100 mA do not cause SCR latch-up.

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

THERMAL RESISTANCE

 θ_{JA} is specified for the worst-case conditions, that is, a device soldered in a circuit board for surface-mount packages. These specifications apply to a 4-layer board.

Table 5. Thermal Resistance

Package Type	θιΑ	Ө лс	Unit
64-Lead LQFP	45	11	°C /W

ESD CAUTION



ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

PIN CONFIGURATION AND FUNCTION DESCRIPTIONS

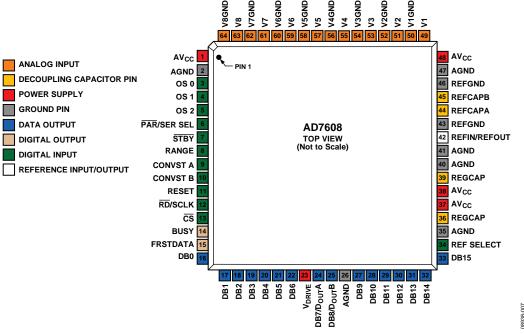


Figure 7. Pin Configuration

Table 6. Pin Function Descriptions

Pin No.	Type ¹	Mnemonic	Description
1, 37, 38, 48	Р	AV cc	Analog Supply Voltage 4.75 V to 5.25 V. This supply voltage is applied to the internal front-end amplifiers and to the ADC core. These supply pins should be decoupled to AGND.
2, 26, 35, 40, 41, 47	Р	AGND	Analog Ground. This pin is the ground reference point for all analog circuitry on the AD7608. All analog input signals and external reference signals should be referred to these pins. All six of these AGND pins should connect to the AGND plane of a system.
5, 4, 3	DI	OS [2: 0]	Oversampling Mode Pins. Logic inputs. These inputs are used to select the oversampling ratio. OS 2 is the MSB control bit, while OS 0 is the LSB control bit. See the Digital Filter section for further details on the oversampling mode of operation and Table 8 for oversampling bit decoding.
6	DI	PAR/SER SEL	Parallel/Serial Interface Selection Input. Logic input. If this pin is tied to a logic low, the parallel interface is selected. If this pin is tied to a logic high, the serial interface is selected. In serial mode, the RD/SCLK pin functions as the serial clock input. The DB7/Dout and DB8/Dout pins function as serial data outputs. When the serial interface is selected, DB[15:9] and DB[6:0] pins should be tied to GND.
7	DI	STBY	Standby Mode Input. This pin is used to place the AD7608 into one of two power-down modes: standby mode or shutdown mode. The power-down mode entered depends on the state of the RANGE pin as shown in Table 7. When in standby mode, all circuitry, except the on-chip reference regulators, and regulator buffers, is powered down. When in shutdown mode, all circuitry is powered down.
8	DI	RANGE	Analog Input Range Selection. Logic input. The polarity on this pin determines the input range of the analog input channels. If this pin is tied to a logic high, the analog input range is $\pm 10\text{V}$ for all channels. If this pin is tied to a logic low, the analog input range is $\pm 5\text{V}$ for all channels. A logic change on this pin has an immediate effect on the analog input range. Changing this pin during a conversion is not recommended. See the Analog Input section for more details.
9, 10	DI	CONVST A, CONVST B	Conversion Start Input A, Conversion Start Input B. Logic inputs. These logic inputs are used to initiate conversions on the analog input channels. For simultaneous sampling of all input channels, CONVST A and CONVST B can be shorted together and a single convert start signal applied. Alternatively, CONVST A can be used to initiate simultaneous sampling for V1, V2, V3, and V4, and CONVST B can be used to initiate simultaneous sampling on the other analog inputs (V5, V6, V7, and V8). This is only possible when oversampling is not switched on. When the CONVST A or CONVST B pin transitions from low to high, the front-end track-and-hold circuitry for their respective analog inputs is set to hold. This function allows a phase delay to be created inherently between the sets of analog inputs.

Pin No.	Type ¹	Mnemonic	Description
11	DI	RESET	Reset Input. When set to logic high, the rising edge of RESET resets the AD7608. Once twake-up has elapsed, the part should receive a RESET pulse after power up. The RESET high pulse should be typically 100 ns wide. If a RESET pulse is applied during a conversion, the conversion is aborted. If a RESET pulse is applied during a read, the contents of the output registers resets to all zeros.
12	DI	RD/SCLK	Parallel Data Read Control Input when Parallel Interface is Selected (RD)/Serial Clock Input when the Serial Interface is Selected (SCLK). When both CS and RD are logic low in parallel mode, the output bus is enabled. In parallel mode, two RD pulses are required to read the full 18 bits of conversion results from each channel. The first RD pulse outputs DB[17:2], the second RD pulse outputs DB[1:0]. In serial mode, this pin acts as the serial clock input for data transfers. The CS falling edge takes the data output lines, Dout A and Dout B, out of three-state and clocks out the MSB of the conversion result. The rising edge of SCLK clocks all subsequent data bits onto the Dout A and Dout B serial data outputs. For further information, see the Conversion Control section.
13	DI	<u>CS</u>	Chip Select. This active low logic input frames the data transfer. When both \overline{CS} and \overline{RD} are logic low in parallel mode, the output bus, DB[15:0], is enabled and the conversion result is output on the parallel data bus lines. In serial mode, the \overline{CS} is used to frame the serial read transfer and clock out the MSB of the serial output data.
14	DO	BUSY	Busy Output. This pin transitions to a logic high after both CONVST A and CONVST B rising edges and indicates that the conversion process has started. The BUSY output remains high until the conversion process for all channels is complete. The falling edge of BUSY signals that the conversion data is being latched into the output data registers and is available to be read after a Time t ₄ . Any data read while BUSY is high must be complete before the falling edge of BUSY occurs. Rising edges on CONVST A or CONVST B have no effect while the BUSY signal is high.
15	DO	FRSTDATA	Digital Output. The FRSTDATA output signal indicates when the first channel, V1, is being read back on either the parallel or serial interface. When the \overline{CS} input is high, the FRSTDATA output pin is in three-state. The falling edge of \overline{CS} takes FRSTDATA out of three-state. In parallel mode, the falling edge of \overline{RD} corresponding to the result of V1 then sets the FRSTDATA pin high indicating that the result from V1 is available on the output data bus. The FRSTDATA output returns to a logic low following the third falling edge of \overline{RD} . In serial mode, FRSTDATA goes high on the falling edge of \overline{CS} as this clocks out the MSB of V1 on $D_{OUT}A$. It returns low on the 18th SCLK falling edge after the \overline{CS} falling edge. See the Conversion Control section for more details.
22 to 16	DO	DB[6:0]	Parallel Output Data Bits, DB6 to DB0. When \overline{PAR}/SER SEL = 0, these pins act as three-state parallel digital output pins. When \overline{CS} and \overline{RD} are low, these pins are used to output DB8 to DB2 of the conversion result during the first \overline{RD} pulse and output 0 during the second \overline{RD} pulse. When \overline{PAR}/SER SEL = 1, these pins should be tied to GND.
23	P	V _{DRIVE}	Logic Power Supply Input. The voltage (2.3 V to 5.25 V) supplied at this pin determines the operating voltage of the interface. This pin is nominally at the same supply as the supply of the host interface (that is, DSP and FPGA).
24	DO	DB7/DoutA	Parallel Output Data Bit 7 (DB7)/Serial Interface Data Output Pin ($\underline{D}_{OUT}A$). When \overline{PAR}/SER SEL = 0, this pin acts as a three-state parallel digital output pin. When \overline{CS} and \overline{RD} are low, this pin is used to output DB9 of the conversion result. When \overline{PAR}/SER SEL = 1, this pin functions as $D_{OUT}A$ and outputs serial conversion data. See the Conversion Control section for further details.
25	DO	DB8/D _{out} B	Parallel Output Data Bit 8 (DB8)/Serial Interface Data Output Pin ($D_{OUT}B$). When \overline{PAR} /SER SEL = 0, this pin acts as a three-state parallel digital output pin. When \overline{CS} and \overline{RD} are low, this pin is used to output DB10 of the conversion result. When \overline{PAR} /SER SEL = 1, this pin functions as $D_{OUT}B$ and outputs serial conversion data. See the Conversion Control section for further details.
31 to 27	DO	DB[13:9]	Parallel Output Data Bits, DB13 to DB9. When $\overline{\text{PAR}}/\text{SER SEL} = 0$, these pins act as three-state parallel digital output pins. When $\overline{\text{CS}}$ and $\overline{\text{RD}}$ are low, these pins are used to output DB15 to DB11 of the conversion result during the first $\overline{\text{RD}}$ pulse and output zero during the second $\overline{\text{RD}}$ pulse. When $\overline{\text{PAR}}/\text{SER SEL} = 1$, these pins should be tied to GND.
32	DO/DI	DB14	Parallel Output Data Bit 14 (DB14). When PAR/SER SEL = 0, this pin act as three-state parallel digital output pin. When CS and RD are low, this pin is used to output DB16 of the conversion result during the first RD pulse and DB0 of the same conversion result during the second RD pulse. When PAR/SER SEL = 1, this pins should be tied to GND.
33	DO/DI	DB15	Parallel Output Data Bit 15 (DB15). When \overline{PAR}/SER SEL = 0, this pin acts as three-state parallel digital output pin. This pin is used to output DB17 of the conversion result during the first \overline{RD} pulse and DB1 of the same conversion result during the second \overline{RD} pulse. When \overline{PAR}/SER SEL = 1, this pins should be tied to GND.

Pin No.	Type ¹	Mnemonic	Description
34	DI	REF SELECT	Internal/External Reference Selection Input. Logic input. If this pin is set to logic high then the internal reference is selected and is enabled, if this pin is set to logic low then the internal reference is disabled and an external reference voltage must be applied to the REFIN/REFOUT pin.
36, 39	P	REGCAP	Decoupling Capacitor Pins for Voltage Output from Internal Regulator. These output pins should be decoupled separately to AGND using a 1 μ F capacitor. The voltage on these output pins is in the range of 2.5 V to 2.7 V.
42	REF	REFIN/ REFOUT	Reference Input/Reference Output. The on-chip reference of 2.5 V is available on this pin for external use if the REF SELECT pin is set to a logic high. Alternatively, the internal reference can be disabled by setting the REF SELECT pin to a logic low and an external reference of 2.5 V can be applied to this input. See the Internal/External Reference section. Decoupling is required on this pin for both the internal or external reference options. A 10 μ F capacitor should be applied from this pin to ground close to the REFGND pins.
43, 46	REF	REFGND	Reference Ground Pins. These pins should be connected to AGND.
44, 45	REF	REFCAPA, REFCAPB	Reference Buffer Output Force/Sense Pins. These pins must be connected together and decoupled to AGND using a low ESR 10 µF ceramic capacitor.
49, 51, 53, 55, 57, 59, 61, 63	Al	V1 to V8	Analog Inputs. These pins are single-ended analog inputs. The analog input range of these channels is determined by the RANGE pin.
50, 52, 54, 56, 58, 60, 62, 64	AI/ GND	V1GND to V8GND	Analog Input Ground Pins. These pins correspond to the V1 to V8 analog input pins. Connect all analog input AGND pins to the AGND plane of a system.

¹ Refers to classification of pin type; P denotes power, Al denotes analog input, REF denotes reference, DI denotes digital input, DO denotes digital output.

TYPICAL PERFORMANCE CHARACTERISTICS

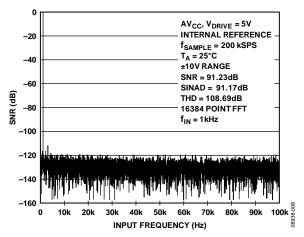


Figure 8. FFT Plot, ±10 V Range

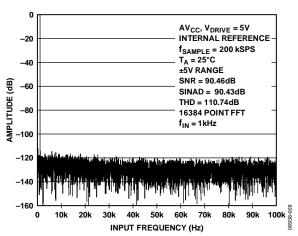


Figure 9. FFT Plot, ±5 V Range

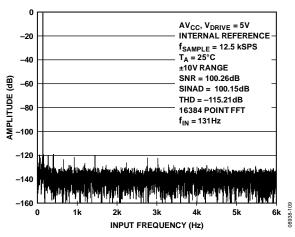


Figure 10. FFT Over Sampling by 16, ±10 V Range

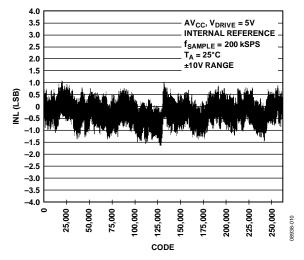


Figure 11. Typical INL, ±10 V Range

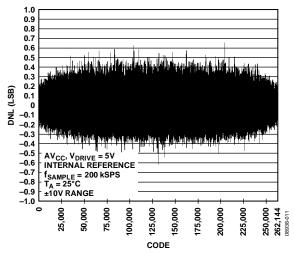


Figure 12. Typical DNL, ±10 V Range

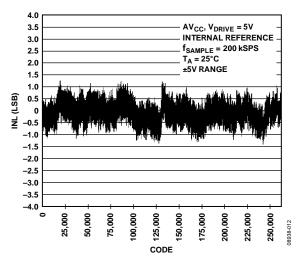


Figure 13. Typical INL, ±5 V Range

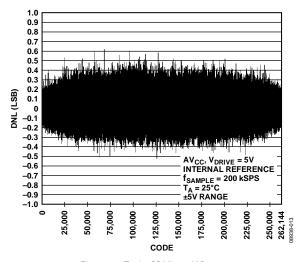


Figure 14. Typical DNL, ±5 V Range

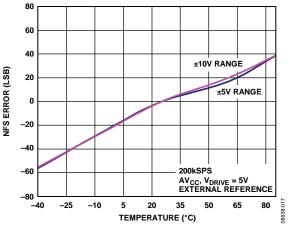


Figure 15. NFS Error vs. Temperature

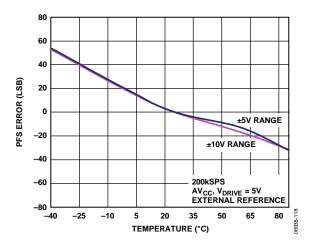


Figure 16. PFS Error vs. Temperature

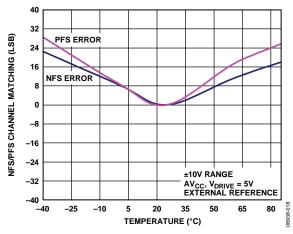


Figure 17. NFS/PFS Error Matching

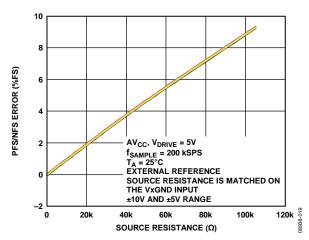


Figure 18. PFS/NFS Error vs. Source Resistance

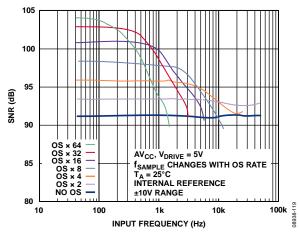


Figure 19. SNR vs. Input Frequency for Different Oversampling Rates, $\pm 10 V$

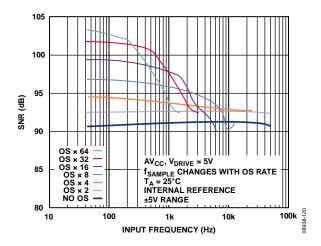


Figure 20. SNR vs. Input Frequency for Different Oversampling Rates, ± 5 V Range

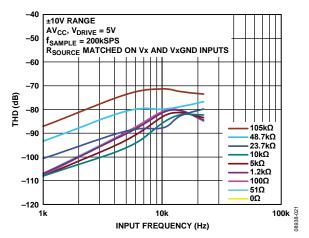


Figure 21. THD vs. Input Frequency for Various Source Impedances, $\pm 10 \, V$ Range

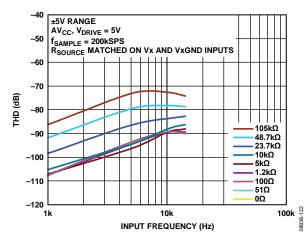


Figure 22. THD vs. Input Frequency for Various Source Impedances, ±5 V Range

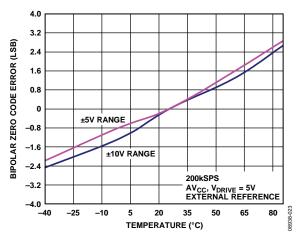


Figure 23. Bipolar Zero Code Error vs. Temperature

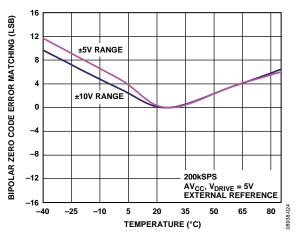


Figure 24. Bipolar Zero Code Error Matching Between Channels

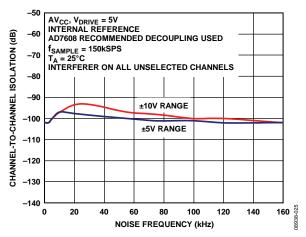


Figure 25. Channel-to-Channel Isolation

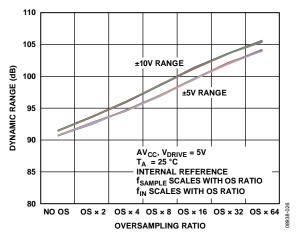


Figure 26. Dynamic Range vs. Oversampling Ratio

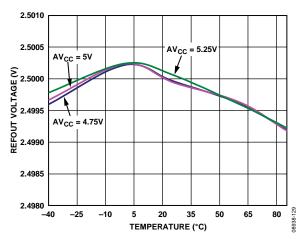


Figure 27. Reference Output Voltage vs. Temperature for Different Supply Voltages

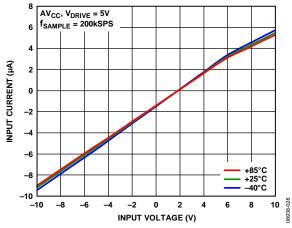


Figure 28. Analog Input Current vs. Input Voltage Across Temperature

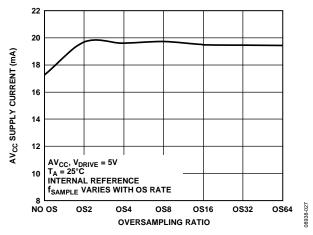


Figure 29. Supply Current vs. Oversampling Rate

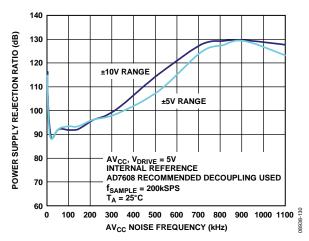


Figure 30. PSRR

TERMINOLOGY

Integral Nonlinearity

The maximum deviation from a straight line passing through the endpoints of the ADC transfer function. The endpoints of the transfer function are zero scale, at ½ LSB below the first code transition; and full scale, at ½ LSB above the last code transition.

Differential Nonlinearity

The difference between the measured and the ideal 1 LSB change between any two adjacent codes in the ADC.

Bipolar Zero Code Error

The deviation of the midscale transition (all 1s to all 0s) from the ideal, which is 0 V $-\frac{1}{2}$ LSB.

Bipolar Zero Code Error Match

The absolute difference in bipolar zero code error between any two input channels.

Positive Full-Scale Error

The deviation of the actual last code transition from the ideal last code transition ($10 \text{ V} - 1\frac{1}{2} \text{ LSB}$ (9.99988) and $5 \text{ V} - 1\frac{1}{2} \text{ LSB}$ (4.99994)) after bipolar zero code error is adjusted out. The positive full-scale error includes the contribution from the internal reference buffer.

Positive Full-Scale Error Match

The absolute difference in positive full-scale error between any two input channels.

Negative Full-Scale Error

The deviation of the first code transition from the ideal first code transition ($-10 \text{ V} + \frac{1}{2} \text{ LSB}$ (-9.99996) and $-5 \text{ V} + \frac{1}{2} \text{ LSB}$ (-4.99998)) after the bipolar zero code error is adjusted out. The negative full-scale error includes the contribution from the internal reference buffer.

Negative Full-Scale Error Match

The absolute difference in negative full-scale error between any two input channels.

Signal-to-(Noise + Distortion) Ratio

The measured ratio of signal-to-(noise + distortion) at the output of the ADC. The signal is the rms amplitude of the fundamental. Noise is the sum of all nonfundamental signals up to half the sampling frequency ($f_s/2$, excluding dc).

The ratio depends on the number of quantization levels in the digitization process; the more levels, the smaller the quantization noise.

The theoretical signal-to-(noise + distortion) ratio for an ideal N-bit converter with a sine wave input is given by

Signal-to-(Noise + Distortion) = (6.02 N + 1.76) dB

Thus, for an 18-bit converter, the signal-to-(noise + distortion) is 110.12 dB.

Total Harmonic Distortion (THD)

The ratio of the rms sum of the harmonics to the fundamental. For the AD7608, it is defined as

THD (dB) =
$$20\log \frac{\sqrt{V_2^2 + V_3^2 + V_4^2 + V_5^2 + V_6^2 + V_7^2 + V_8^2 + V_9^2}}{V_4}$$

where:

 V_1 is the rms amplitude of the fundamental.

 V_2 to V_9 are the rms amplitudes of the second through ninth harmonics.

Peak Harmonic or Spurious Noise

The ratio of the rms value of the next largest component in the ADC output spectrum (up to $f_s/2$, excluding dc) to the rms value of the fundamental. Normally, the value of this specification is determined by the largest harmonic in the spectrum, but for ADCs where the harmonics are buried in the noise floor, it is determined by a noise peak.

Intermodulation Distortion (IMD)

With inputs consisting of sine waves at two frequencies, fa and fb, any active device with nonlinearities creates distortion products at sum and difference frequencies of mfa \pm nfb, where m, n = 0, 1, 2, 3. Intermodulation distortion terms are those for which neither m nor n is equal to 0. For example, the second-order terms include (fa + fb) and (fa – fb), and the third-order terms include (2fa + fb), (2fa – fb), (fa + 2fb), and (fa – 2fb).

The calculation of the intermodulation distortion is per the THD specification, where it is the ratio of the rms sum of the individual distortion products to the rms amplitude of the sum of the fundamentals expressed in decibels (dB).

Power Supply Rejection Ratio (PSRR)

Variations in power supply affect the full-scale transition but not the converter's linearity. PSR is the maximum change in full-scale transition point due to a change in power supply voltage from the nominal value. The PSR ratio (PSRR) is defined as the ratio of the power in the ADC output at full-scale frequency, f, to the power of a 100 mV p-p sine wave applied to the ADC's $V_{\rm DD}$ and V_{SS} supplies of Frequency $f_{\rm S}$.

$$PSRR (dB) = 10 \log (Pf/Pf_s)$$

where:

Pf is equal to the power at Frequency f in the ADC output. Pf_S is equal to the power at Frequency f_S coupled onto the AV_{CC} supply.

Channel-to-Channel Isolation

Channel-to-channel isolation is a measure of the level of crosstalk between all input channels. It is measured by applying a full-scale sine wave signal, up to 160 kHz, to all unselected input channels and then determining the degree to which the signal attenuates in the selected channel with a 1 kHz sine wave signal applied (see Figure 25).

THEORY OF OPERATION CONVERTER DETAILS

The AD7608 is a data acquisition system that employs a high speed, low power, charge redistribution, successive approximation analog-to-digital converter (ADC) and allows the simultaneous sampling of eight analog input channels. The analog inputs on the AD7608 can accept true bipolar input signals. The RANGE pin is used to select either $\pm 10~\rm V$ or $\pm 5~\rm V$ as the input range. The AD7608 operates from a single $5~\rm V$ supply.

The AD7608 contains input clamp protection, input signal scaling amplifiers, a second-order antialiasing filter, track-and-hold amplifiers, an on-chip reference, reference buffers, a high speed ADC, a digital filter, and high speed parallel and serial interfaces. Sampling on the AD7608 is controlled using the CONVST x signals.

ANALOG INPUT

Analog Input Ranges

The AD7608 can handle true bipolar, single-ended input voltages. The logic level on the RANGE pin determines the analog input range of all analog input channels. If this pin is tied to a logic high, the analog input range is $\pm 10~V$ for all channels. If this pin is tied to a logic low, the analog input range is $\pm 5~V$ for all channels. A logic change on the RANGE pin has an immediate effect on the analog input range; however, there is typically a settling time of approximately 80 μs , in addition to the normal acquisition time requirement. The recommended practice is to hardwire the RANGE pin according to the desired input range for the system signals.

During normal operation, the applied analog input voltage should remain within the analog input range selected via the range pin. A RESET pulse must be applied after power-up to ensure the analog input channels are configured for the range selected.

When in a power-down mode, it is recommended to tie the analog inputs to GND. As per the Analog Input Clamp Protection section, the overvoltage clamp protection is recommended for use in transient overvoltage conditions and should not remain active for extended periods. Stressing the analog inputs outside of the conditions mentioned here may degrade the Bipolar Zero Code error and THD performance of the AD7608.

Analog Input Impedance

The analog input impedance of the AD7608 is 1 M Ω . This is a fixed input impedance that does not vary with the AD7608 sampling frequency. This high analog input impedance eliminates the need for a driver amplifier in front of the AD7608, allowing for direct connection to the source or sensor. With the need for a driver amplifier eliminated, bipolar supplies (which are often a source of noise in a system) can be removed from the signal chain.

Analog Input Clamp Protection

Figure 31 shows the analog input structure of the AD7608. Each AD7608 analog input contains clamp protection circuitry. Despite single 5 V supply operation, this analog input clamp protection allows for an input overvoltage up to ± 16.5 V.

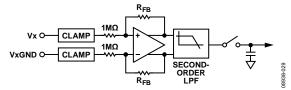


Figure 31. Analog Input Circuitry

Figure 32 shows the voltage vs. current characteristic of the clamp circuit. For input voltages of up to ± 16.5 V, no current flows in the clamp circuit. For input voltages that are above ± 16.5 V, the AD7608 clamp circuitry turns on.

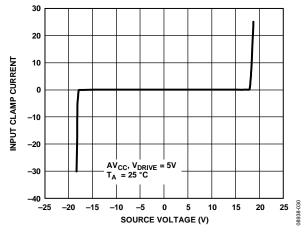


Figure 32. Input Protection Clamp Profile

A series resistor should be placed on the analog input channels to limit the current to ± 10 mA for input voltages above ± 16.5 V. In an application where there is a series resistance on an analog input channel, Vx, a corresponding resistance is required on the analog input GND channel, VxGND (see Figure 33). If there is no corresponding resistor on the VxGND channel, an offset error occurs on that channel.

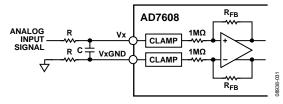


Figure 33. Input Resistance Matching on the Analog Input

Analog Input Antialiasing Filter

An analog antialiasing filter (a second-order Butterworth) is also provided on the AD7608. Figure 34 and Figure 35 show the frequency and phase response, respectively, of the analog antialiasing filter. In the ± 5 V range, the -3 dB frequency is typically 15 kHz. In the ± 10 V range, the -3 dB frequency is typically 23 kHz.

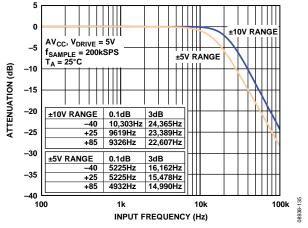


Figure 34. Analog Antialiasing Filter Frequency Response

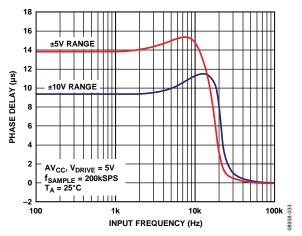


Figure 35. Analog Antialiasing Filter Phase Response

Track-and-Hold Amplifiers

The track-and-hold amplifiers on the AD7608 allow the ADC to accurately acquire an input sine wave of full-scale amplitude to 18-bit resolution. The track-and-hold amplifiers sample their respective inputs simultaneously on the rising edge of CONVST x. The aperture time for track-and-hold (that is, the delay time between the external CONVST x signal and the

track-and-hold actually going into hold) is well matched, by design, across all eight track-and-holds on one device and from device to device. This matching allows more than one AD7608 device to be sampled simultaneously in a system.

The end of the conversion process across all eight channels is indicated by the falling edge of BUSY; and it is at this point that the track-and-holds return to track mode, and the acquisition time for the next set of conversions begins.

The conversion clock for the part is internally generated, and the conversion time for all channels is 4 μs on the AD7608. The BUSY signal returns low after all eight conversions to indicate the end of the conversion process. On the falling edge of BUSY, the track-and-hold amplifiers return to track mode. New data can be read from the output register via the parallel or serial interface after BUSY goes low; or, alternatively, data from the previous conversion can be read while BUSY is high. Reading data from the AD7608 while a conversion is in progress has little effect on performance and allows a faster throughput to be achieved. In parallel mode at $V_{\rm DRIVE} > 3.3$ V, the SNR is reduced by $\sim\!1.5$ dB when reading during a conversion.

ADC TRANSFER FUNCTION

The output coding of the AD7608 is twos complement. The designed code transitions occur midway between successive integer LSB values, that is, 1/2 LSB, 3/2 LSB. The LSB size is FSR/262,144 for the AD7608. The ideal transfer characteristic for the AD7608 is shown in Figure 36.

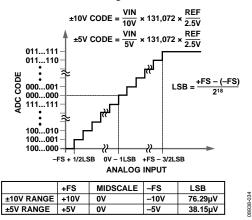


Figure 36. AD7608 Transfer Characteristic

The LSB size is dependent on the analog input range selected.

INTERNAL/EXTERNAL REFERENCE

The AD7608 contains an on-chip 2.5 V band gap reference. The REFIN/REFOUT pin allows access to the 2.5 V reference that generates the on-chip 4.5 V reference internally, or it allows an external reference of 2.5 V to be applied to the AD7608. An externally applied reference of 2.5 V is also gained up to 4.5 V, using the internal buffer. This 4.5 V buffered reference is the reference used by the SAR ADC.

The REF SELECT pin is a logic input pin that allows the user to select between the internal reference or an external reference. If this pin is set to logic high, the internal reference is selected and enabled. If this pin is set to logic low, the internal reference is disabled and an external reference voltage must be applied to the REFIN/REFOUT pin. The internal reference buffer is always enabled. After a reset, the AD7608 operates in the reference mode selected by the REF SELECT pin. Decoupling is required on the REFIN/REFOUT pin for both the internal and external reference options. A 10 μF ceramic capacitor is required on the REFIN/REFOUT pin.

The AD7608 contains a reference buffer configured to gain the REF voltage up to ${\sim}4.5$ V, as shown in Figure 37. The REFCAPA and REFCAPB pins must be shorted together externally, and a ceramic capacitor of 10 μF applied to REFGND, to ensure that the reference buffer is in closed-loop operation. The reference voltage available at the REFIN/REFOUT pin is 2.5 V.

When the AD7608 is configured in external reference mode, the REFIN/REFOUT pin is a high input impedance pin. For applications using multiple AD7608 devices, the following configurations are recommended, depending on the application requirements.

External Reference Mode

One ADR421 external reference can be used to drive the REFIN/REFOUT pins of all AD7608 devices (see Figure 38). In this configuration, each REFIN/REFOUT pin of the AD7608 should be decoupled with at least a 100 nF decoupling capacitor.

Internal Reference Mode

One AD7608 device, configured to operate in the internal reference mode, can be used to drive the remaining AD7608 devices, which are configured to operate in external reference mode (see Figure 39). The REFIN/REFOUT pin of the AD7608, configured in internal reference mode, should be decoupled using a 10 μF ceramic decoupling capacitor. The other AD7608 devices, configured in external reference mode, should use at least a 100 nF decoupling capacitor on their REFIN/REFOUT pins.

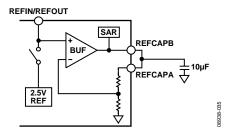


Figure 37. Reference Circuitry

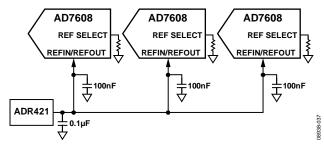


Figure 38. Single External Reference Driving Multiple AD7608 REFIN Pins

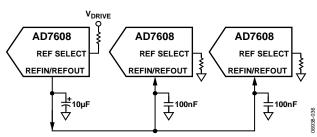


Figure 39. Internal Reference Driving Multiple AD7608 REFIN Pins

TYPICAL CONNECTION DIAGRAM

Figure 40 shows the typical connection diagram for the AD7608. There are four AVCC supply pins on the part, and each of the four pins should be decoupled using a 100 nF capacitor at each supply pin and a 10 μF capacitor at the supply source. The AD7608 can operate with the internal reference or an externally applied reference. In this configuration, the AD7608 is configured to operate with the internal reference. When using a single AD7608 device on the board, the REFIN/REFOUT pin should be decoupled with a 10 μF capacitor. Refer to the Internal/External Reference section when using an application with multiple AD7608 devices. The REFCAPA and REFCAPB pins are shorted together and decoupled with a 10 μF ceramic capacitor.

The V_{DRIVE} supply is connected to the same supply as the processor. The V_{DRIVE} voltage controls the voltage value of the output logic signals. For layout, decoupling, and grounding hints, see the Layout Guidelines section.

After supplies have been applied to the AD7608, apply a RESET signal to the device to ensure it is configured for the correct mode of operation.

POWER-DOWN MODES

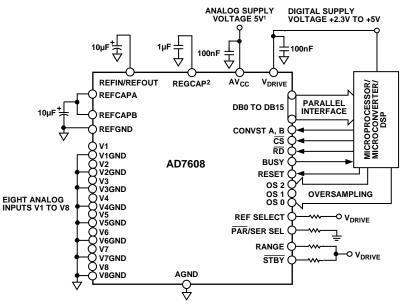
There are two power-down modes available on the AD7608: standby mode and shutdown mode. The STBY pin controls whether the AD7608 is in normal mode or in one of the two power-down modes.

The power-down mode is selected through the state of the RANGE pin when the \overline{STBY} pin is low. Table 7 shows the configurations required to choose the desired power-down mode. When the AD7608 is placed in standby mode, the current consumption is 8 mA maximum and power-up time is approximately 100 μ s because the capacitor on the REFCAPA and REFCAPB pins must charge up. In standby mode, the on-chip reference and regulators remain powered up, and the amplifiers and ADC core are powered down.

When the AD7608 is placed in shutdown mode, the current consumption is 11 μ A maximum and power-up time is approximately 13 ms (external reference mode). In shutdown mode, all circuitry is powered down. When the AD7608 is powered up from shutdown mode, a RESET signal must be applied to the AD7608 after the required power-up time has elapsed.

Table 7. Power-Down Mode Selection

Power-Down Mode	STBY	RANGE
Standby	0	1
Shutdown	0	0



 $^1\text{DECOUPLING}$ SHOWN ON THE AV $_{\text{CC}}$ PIN APPLIES TO EACH AV $_{\text{CC}}$ PIN (PIN 1, PIN 37, PIN 38, PIN 48). DECOUPLING CAPACITOR CAN BE SHARED BETWEEN AV $_{\text{CC}}$ PIN 37 AND PIN 38. $^2\text{DECOUPLING}$ SHOWN ON THE REGCAP PIN APPLIES TO EACH REGCAP PIN (PIN 36, PIN 39).

Figure 40. Typical Connection Diagram

CONVERSION CONTROL

Simultaneous Sampling on All Analog Input Channels

The AD7608 allows simultaneous sampling of all analog input channels. All channels are sampled simultaneously when both CONVST x pins (CONVST A, CONVST B) are tied together. A single CONVST x signal is used to control both CONVST x inputs. The rising edge of this common CONVST x signal initiates simultaneous sampling on all analog input channels.

The AD7608 contains an on-chip oscillator that is used to perform the conversions. The conversion time for all ADC channels is $t_{\rm CONV}$. The BUSY signal indicates to the user when conversions are in progress, so when the rising edge of CONVST x is applied, BUSY goes logic high and transitions low at the end of the entire conversion process. The falling edge of the BUSY signal is used to place all eight track-and-hold amplifiers back into track mode. The falling edge of BUSY also indicates that the new data can now be read from the parallel bus (DB[15:0]), or the $D_{\rm OUT}A$ and $D_{\rm OUT}B$ serial data lines.

Simultaneously Sampling Two Sets of Channels

The AD7608 also allows the analog input channels to be sampled simultaneously in two sets. This can be used in power-line protection and measurement systems to compensate for phase differences introduced by PT and CT transformers. In a 50 Hz system, this allows for up to 9° of phase compensation; and in a 60 Hz system, it allows for up to 10° of phase compensation.

This is accomplished by pulsing the two CONVST x pins independently and is possible only if oversampling is not in use. CONVST A is used to initiate simultaneous sampling of the first set of channels (V1 to V4) and CONVST B is used to initiate simultaneous sampling on the second set of analog input channels (V5 to V8), as illustrated in Figure 41. On the rising edge of CONVST A, the track-and-hold amplifiers for the first set of channels are placed into hold mode. On the rising edge of CONVST B, the track-and-hold amplifiers for the second set of channels are placed into hold mode. The conversion process begins once both rising edges of CONVST x have occurred; therefore BUSY goes high on the rising edge of the later CONVST x signal. In Table 3, Time t₅ indicates the maximum allowable time between CONVST x sampling points.

There is no change to the data read process when using two separate CONVST x signals.

Connect all unused analog input channels to AGND. The results for any unused channels are still included in the data read because all channels are always converted.

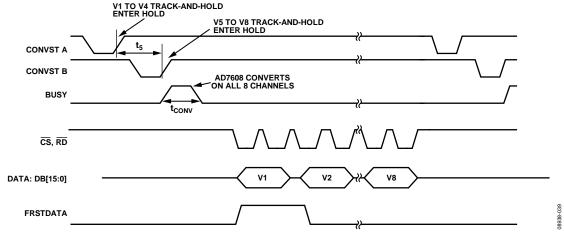


Figure 41. Simultaneous Sampling on Channel Sets Using Independent CONVST A/CONVST B Signals—Parallel Mode

DIGITAL INTERFACE

The AD7608 provides two interface options: a parallel interface and high speed <u>serial</u> interface. The required interface mode is selected via the PAR/SER SEL pin.

The operation of the interface modes is discussed in the following sections.

PARALLEL INTERFACE ($\overline{PAR}/SER SEL = 0$)

Data can be read from the AD7608 via the parallel data bus with standard \overline{CS} and \overline{RD} signals. To read the data over the parallel bus, the \overline{PAR}/SER SEL pin should be tied low. The \overline{CS} and \overline{RD} input signals are internally gated to enable the conversion result onto the data bus. The data \overline{Lines} , $\overline{DB15}$ to $\overline{DB0}$, leave their high impedance state when both \overline{CS} and \overline{RD} are logic low.

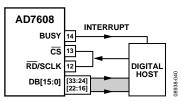


Figure 42. AD7608 interface diagram—One AD7608 Using the Parallel Bus; $\overline{\text{CS}}$ and $\overline{\text{RD}}$ Shorted Together

The rising edge of the $\overline{\text{CS}}$ input signal three-states the bus and the falling edge of the $\overline{\text{CS}}$ input signal takes the bus out of the high impedance state. $\overline{\text{CS}}$ is the control signal that enables the data lines, it is the function that allows multiple AD7608 devices to share the same parallel data bus.

The $\overline{\text{CS}}$ signal can be permanently tied low, and the $\overline{\text{RD}}$ signal can be used to access the conversion results as shown in Figure 4. A read operation of new data can take place after the BUSY signal goes low (Figure 2), or alternatively a read operation of data from the previous conversion process can take place while BUSY is high (Figure 3).

The \overline{RD} pin is used to read data from the output conversion results register. Two \overline{RD} pulses are required to read the full 18-bit conversion result from each channel. Applying a sequence of $16\ \overline{RD}$ pulses to the AD7608 \overline{RD} pin clocks the conversion results out from each channel onto the 16-bit parallel output bus in ascending order. The first \overline{RD} falling edge after BUSY goes low clocks out DB[17:2] of the V1 result, the next \overline{RD} falling edge updates the bus with DB[1:0] of V1 result. It takes $16\ \overline{RD}$ pulses to read the eight 18-bit conversion results from the AD7608. On the AD7608, the 16^{th} falling edge of \overline{RD} clocks out the DB[1:0] conversion result for Channel V8. When the \overline{RD} signal is logic low, it enables the data conversion result from each channel to be transferred to the digital host (DSP, FPGA).

When there is only one AD7608 in a system/board and it does not share the parallel bus, data can be read using just one control signal from the digital host. The $\overline{\text{CS}}$ and $\overline{\text{RD}}$ signals can be tied together as shown in Figure 5. In this case, the data bus comes out of three-state on the falling edge of $\overline{\text{CS}/\text{RD}}$. The combined $\overline{\text{CS}}$ and $\overline{\text{RD}}$ signal allows the data to be clocked out of the AD7608 and to be read by the digital host. In this case, $\overline{\text{CS}}$ is used to frame the data transfer of each data channel. In this case, $16\ \overline{\text{CS}}$ pulses are required to read the eight channels of data.

SERIAL INTERFACE ($\overline{PAR}/SER SEL = 1$)

To read data back from the AD7608 over the serial interface, the \overline{PAR}/SER SEL pin should be tied high. The \overline{CS} and SCLK signals are used to transfer data from the AD7608. The AD7608 has two serial data output pins, $D_{OUT}A$, and $D_{OUT}B$. Data can be read back from the AD7608 using one or both of these D_{OUT} lines. For the AD7608, conversion results from Channel V1 to Channel V4 first appear on DOUTA while conversion results from Channel V5 to Channel V8 first appear on $D_{OUT}B$.

The $\overline{\text{CS}}$ falling edge takes the data output lines (DoutA and DoutB) out of three-state and clocks out the MSB of the conversion result. The rising edge of SCLK clocks all subsequent data bits onto the serial data outputs, DoutA and DoutB. The $\overline{\text{CS}}$ input can be held low for the entire serial read, or it can be pulsed to frame each channel read of 18 SCLK cycles.

Figure 43 shows a read of eight simultaneous conversion results using two D_{OUT} lines on the AD7608. In this case, a 72 SCLK transfer is used to access data from the AD7608 and CS is held low to frame the entire 72 SCLK cycles. Data can also be clocked out using just one Dout line, in which case Dout A is recommended to access all conversion data as the channel data is output in ascending order. For the AD7608 to access all eight conversion results on one D_{OUT} line, a total of 144 SCLK cycles are required. These 144 SCLK cycles can be framed by one CS signal or each group of 18 SCLK cycles can be individually framed by the CS signal. The disadvantage of using just one D_{OUT} line is that the throughput rate is reduced if reading after conversion. The unused DOUT line should be left unconnected in serial mode. For the AD7608, if DOUTB is used as a single DOUT line, the channel results will output in the following order: V5, V6, V7, V8, V1, V2, V3, V4; however, the FRSTDATA indicator returns low once V5 is read on DOUTB.

Figure 6 shows the timing diagram for reading one channel of data, framed by the $\overline{\text{CS}}$ signal, from the AD7608 in serial mode.

The SCLK input signal provides the clock source for the serial read operation. \overline{CS} goes low to access the data from the AD7608. The falling edge of \overline{CS} takes the bus out of three-state and clocks out the MSB of the 18-bit conversion result. This MSB is valid on the first falling edge of the SCLK after the \overline{CS} falling edge. The subsequent 17 data bits are clocked out of the AD7608 on the SCLK rising edge. Data is valid on the SCLK falling edge. Eighteen clock cycles must be provided to the AD7608 to access each conversion result.

The FRSTDATA output signal indicates when the first channel, V1, is being read back. When the $\overline{\text{CS}}$ input is high, the FRSTDATA output pin is in three-state. In serial mode, the falling edge of $\overline{\text{CS}}$ takes FRSTDATA out of three-state and sets the FRSTDATA pin high indicating that the result from V1 is available on the Douth output data line. The FRSTDATA output returns to a logic low following the 18th SCLK falling edge. If all channels are read on Douth, the FRSTDATA output does not go high when V1 is output on the serial data output pin. It only goes high when V1 is available on Douth (and this is when V5 is available on Douth).

READING DURING CONVERSION

Data can be read from the AD7608 while BUSY is high and conversions are in progress. This has little effect on the performance of the converter and allows a faster throughput rate to be achieved. A parallel or serial read may be performed during conversions and when oversampling may or may not be in use. Figure 3 shows the timing diagram for reading while BUSY is high in parallel or serial mode. Reading during conversions allows the full throughput rate to be achieved when using the serial interface with a $V_{\rm DRIVE}$ of 3.3 V to 5.25 V.

Data can be read from the AD7608 at any time other than on the falling edge of BUSY because this is when the output data registers get updated with the new conversion data. Time t₆, as outlined in Table 3, should be observed in this condition.

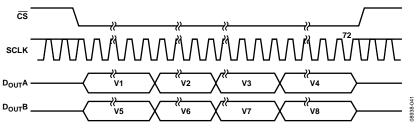


Figure 43. AD7608 Serial Interface with two Dout Lines

DIGITAL FILTER

The AD7608 contains an optional digital first-order sinc filter that should be used in applications where slower throughput rates are used or where higher signal-to-noise ratio or dynamic range is desirable. The oversampling ratio of the digital filter is controlled using the oversampling pins, OS [2:0] (see Table 8). OS 2 is the MSB control bit, and OS 0 is the LSB control bit. Table 8 provides the oversampling bit decoding to select the different oversample rates. The OS pins are latched on the falling edge of BUSY. This sets the oversampling rate for the next conversion (see Figure 45). In addition to the oversampling function, the output result is decimated to 18-bit resolution.

If the OS pins are set to select an OS ratio of 8, the next CONVST x rising edge takes the first sample for each channel, and the remaining seven samples for all channels are taken with an internally generated sampling signal. These samples are then averaged to yield an improvement in SNR performance. Table 8 shows typical SNR performance for both the ± 10 V and the ± 5 V range. As Table 8 indicates, there is an improvement in SNR as the OS ratio increases. As the OS ratio increases, the 3 dB frequency is reduced, and the allowed sampling frequency is also reduced. In an application where the required sampling frequency is 10 kSPS, an OS ratio of up to 16 can be used. In this case, the application sees an improvement in SNR, but the input 3 dB bandwidth is limited to ~ 6 kHz.

The CONVST A and CONVST B pins must be tied/driven together when oversampling is turned on. When the oversampling function is turned on, the BUSY high time for the conversion process extends. The actual BUSY high time depends on the oversampling rate selected: the higher the oversampling rate, the longer the BUSY high, or total conversion time (see Table 3).

Figure 44 shows that the conversion time extends as the oversampling rate is increased, and the BUSY signal lengthens for the different oversampling rates. For example, a sampling frequency of 10 kSPS yields a cycle time of 100 μs . Figure 44 shows OS \times 2 and OS \times 4; for a 10 kSPS example, there is adequate cycle time to further increase the oversampling rate and yield greater improvements in SNR performance. In an application where the initial sampling or throughput rate is at 200 kSPS, for example, and oversampling is turned on, the throughput rate must be reduced to accommodate the longer conversion time and to allow for the read. To achieve the fastest throughput rate possible when oversampling is turned on, the read can be performed during the BUSY high time. The falling edge of BUSY is used to update the output data registers with the new conversion data; therefore, the reading of conversion data should not occur on this edge.

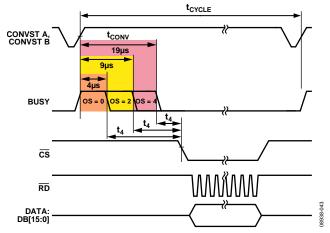


Figure 44. No Oversampling, Oversampling × 2, and Oversampling × 4 While Using Read After Conversion

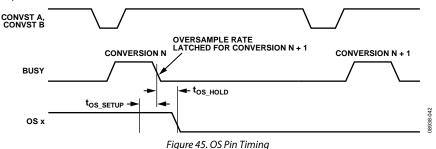


Table 8. Oversample Bit Decoding

OS [2:0]	OS Ratio	SNR ±5 V Range (dB) ¹	SNR ±10 V Range (dB) ¹	3 dB BW ±5 V Range (kHz)	3 dB BW ±10 V Range (kHz)	Maximum Throughput CONVST x Frequency (kHz)
000	No OS	90.5	91.2	15	22	200
001	2	92.5	93.4	15	22	100
010	4	94.45	95.7	13.7	18.5	50
011	8	96.5	98	10.3	11.9	25
100	16	99.1	100.4	6	6	12.5
101	32	101.7	102.8	3	3	6.25
110	64	103	103.5	1.5	1.5	3.125
111	Invalid					

¹ SNR values taken with a full scale 100 Hz input signal.

Figure 46 to Figure 52 illustrates the effect of oversampling on the code spread in a dc histogram plot. As the oversample rate is increased, the spread of codes is reduced. (In Figure 46 to Figure 52, $AV_{CC} = V_{DRIVE} = 5$ V and the sampling rate was scaled with OS ratio.)

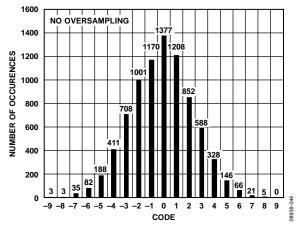


Figure 46. Histogram of Codes—No OS (18 Codes)

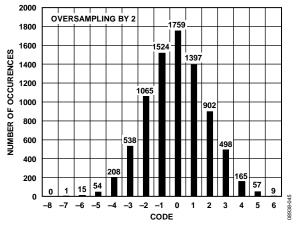


Figure 47. Histogram of Codes—OS × 2 (14 Codes)

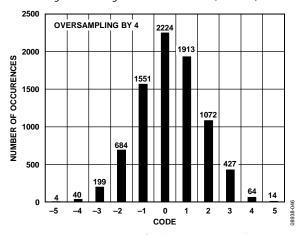


Figure 48. Histogram of Codes—OS \times 4 (11 Codes)

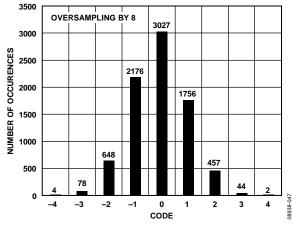


Figure 49. Histogram of Codes—OS × 8 (9 Codes)

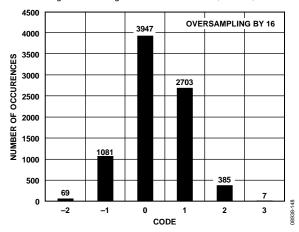


Figure 50. Histogram of Codes—OS × 16 (6 Codes)

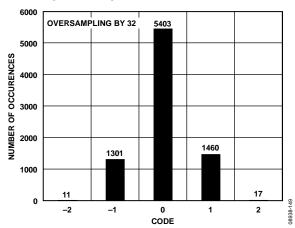


Figure 51. Histogram of Codes—OS × 32 (5 Codes)

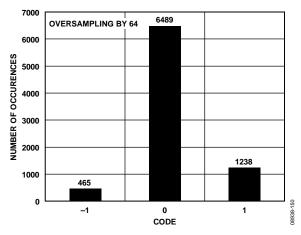


Figure 52. Histogram of Codes—OS × 64 (3 Codes)

When the oversampling mode is selected, this has the effect of adding a digital filter function after the ADC. The different oversampling rates and the CONVST x sampling frequency produces different digital filter frequency profiles.

Figure 53 to Figure 58 show the digital filter frequency profiles for oversampling by 2 to oversampling by 64. The combination of the analog antialiasing filter and the oversampling digital filter can be used to eliminate or reduce the complexity of the design of the filter before the AD7608. The digital filtering combines steep roll-off and linear phase response.

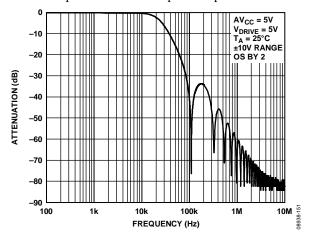


Figure 53. Digital Filter OS \times 2

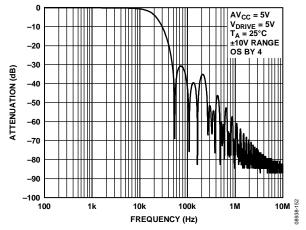


Figure 54. Digital Filter Response for OS × 4

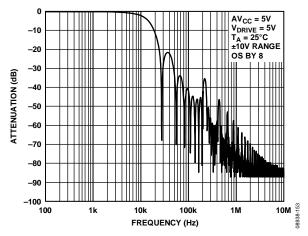


Figure 55. Digital Filter Response for OS \times 8

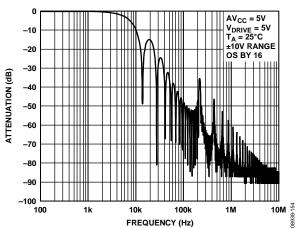


Figure 56. Digital Filter Response for OS \times 16

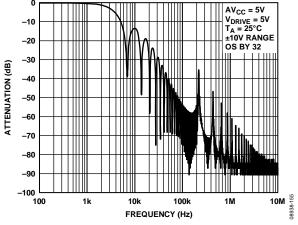


Figure 57. Digital Filter Response for OS \times 32

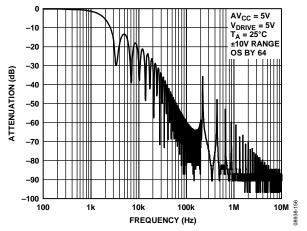


Figure 58. Digital Filter Response for OS \times 64

LAYOUT GUIDELINES

The printed circuit board that houses the AD7608 should be designed so that the analog and digital sections are separated and confined to different areas of the board.

Use at least one ground plane. It can be common or split between the digital and analog sections. In the case of the split plane, the digital and analog ground planes should be joined in only one place, preferably as close as possible to the AD7608.

If the AD7608 is in a system where multiple devices require analog-to-digital ground connections, the connection should still be made at only one point: a star ground point should be established as close as possible to the AD7608. Good connections should be made to the ground plane. Avoid sharing one connection for multiple ground pins. Individual vias or multiple vias to the ground plane should be used for each ground pin.

Avoid running digital lines under the devices because doing so couples noise onto the die. Allow the analog ground plane to run under the AD7608 to avoid noise coupling. Fast switching signals like CONVST A, CONVST B, or clocks should be shielded with digital ground to avoid radiating noise to other sections of the board, and they should never run near analog signal paths. Avoid crossover of digital and analog signals. Run traces on layers in close proximity on the board at right angles to each other to reduce the effect of feedthrough through the board.

The power supply lines to the AV_{CC} and V_{DRIVE} pins on the AD7608 should use as large a trace as possible to provide low impedance paths and reduce the effect of glitches on the power supply lines. Where possible, use supply planes. Good connections should be made between the AD7608 supply pins and the power tracks on the board. Use a single via or multiple vias for each supply pin.

Good decoupling is also important to lower the supply impedance presented to the AD7608 and to reduce the magnitude of the supply spikes. The decoupling capacitors should be placed close to (ideally right up against) these pins and their corresponding ground pins. Place the decoupling capacitors for the REFIN/ REFOUT pin and the REFCAPA and REFCAPB pins as close as possible to their respective AD7608 pins and where possible they should be placed on the same side of the board as the AD7608 device. Figure 59 shows the recommended decoupling on the top layer of the AD7608 board. Figure 60 shows bottom layer decoupling. Bottom layer decoupling is for the four AV $_{\rm CC}$ pins and the V $_{\rm DRIVE}$ pin.

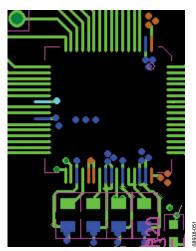


Figure 59. Top Layer Decoupling REFIN/REFOUT, REFCAPA, REFCAPB, and REGCAP Pins

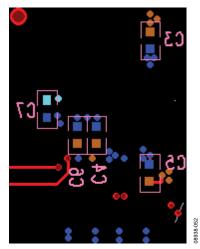


Figure 60. Bottom Layer Decoupling

To ensure good device-to-device performance matching, in a system that contains multiple AD7608 devices, a symmetrical layout between the AD7608 devices is important.

Figure 61 shows a layout with two devices. The AV_{CC} supply plane runs to the right of both devices. The V_{DRIVE} supply track runs to the left of the two devices. The reference chip is positioned between both the two devices and the reference voltage track runs north to Pin 42 of U1 and south to Pin 42 to U2. A solid ground plane is used.

These symmetrical layout principles can be applied to a system that contains more than two AD7608 devices. The AD7608 devices can be placed in a north-south direction with the reference voltage located midway between the AD7608 devices with the reference track running in the north-south direction similar to Figure 61.

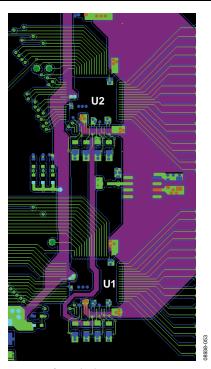
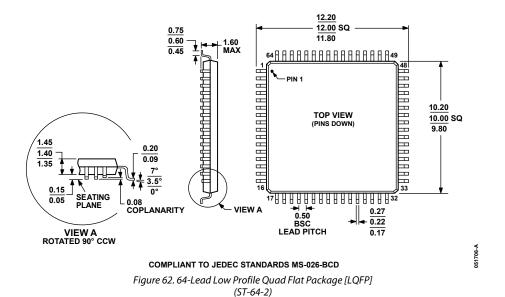


Figure 61. Layout for Multiple AD7608 Devices—Top Layer and Supply Plane Layer

OUTLINE DIMENSIONS



ORDERING GUIDE

ONDERING GOIDE					
Model ¹	Temperature Range	Package Description	Package Option		
AD7608BSTZ	−40°C to +85°C	64-Lead Low Profile Quad Flat Package [LQFP]	ST-64-2		
AD7608BSTZ-RL	-40°C to +85°C	64-Lead Low Profile Quad Flat Package [LQFP]	ST-64-2		
EVAL-AD7608SDZ		Evaluation Board for the AD7608			
EVAL-SDP-CB1Z		Converter Evaluation Development			

Dimensions shown in millimeters

¹ Z = RoHS Compliant Part.



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- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

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